

V-Band Power Amplifier, 58 to 62 GHz, 31 dB Gain, +28 dBm P_{1dB}

Description:

Model SBP-5836233128-VFVF-S1-HR is designed and manufactured for secure communication systems. This product is a power amplifier with a typical small signal gain of 31 dB and a nominal P_{1dB} of +28 dBm across the frequency range of 58 to 62 GHz. The saturated output power of the amplifier is +29 dBm. The DC power requirement for the amplifier is +8 V_{DC}/2.9 A. The input and output ports are both female V connectors. Other port configurations, such as inline and right-angle waveguides, are also available under different model numbers.



Features:

- Broadband Performance
- High Output Power
- High Gain and Good Gain Flatness

Applications:

- IEEE 802.11ab WiGig
- Radar Systems
- Communication Systems

Electrical Specifications:

| Parameter | Minimum | Typical | Maximum |
|---------------------------|--------------------|--------------------|---------------------|
| Frequency | 58 GHz | | 62 GHz |
| Gain | | 31 dB | |
| P _{1dB} | | +28 dBm | |
| P _{sat} | | +29 dBm | |
| P _{in} | | | +22 dBm |
| Input Return Loss | | 10 dB | |
| Output Return Loss | | 8 dB | |
| DC Voltage | +6 V _{DC} | +8 V _{DC} | +15 V _{DC} |
| DC Supply Current | | 2.9 A | |
| Specification Temperature | | +25 °C | |
| Operating Temperature | 0 °C | | +50 °C |

Mechanical Specifications:

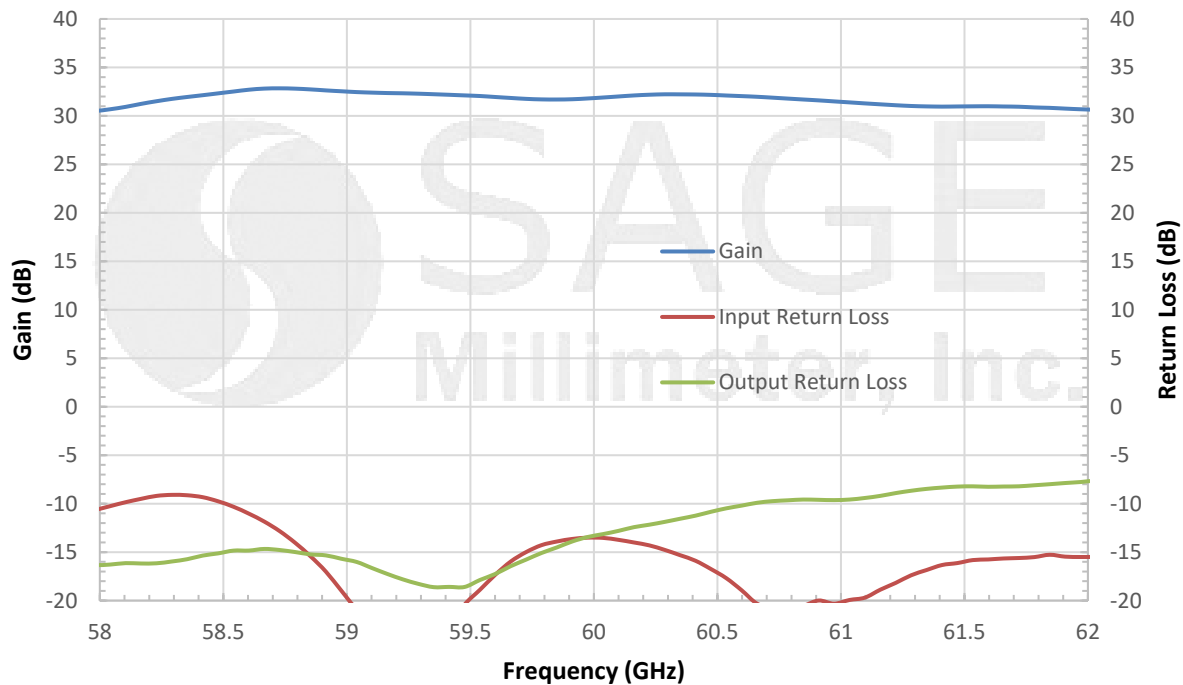
| Item | Specification |
|---------------|-----------------------------------|
| Input Port | V(F) |
| Output Port | V(F) |
| Bias | Solder Pin |
| Case Material | Aluminum |
| Finish | Gold Plated |
| Weight | 17 Oz |
| Size | 3.15" (L) X 3.15" (W) X 3.48" (H) |
| Outline | BK-SC-C1-H |



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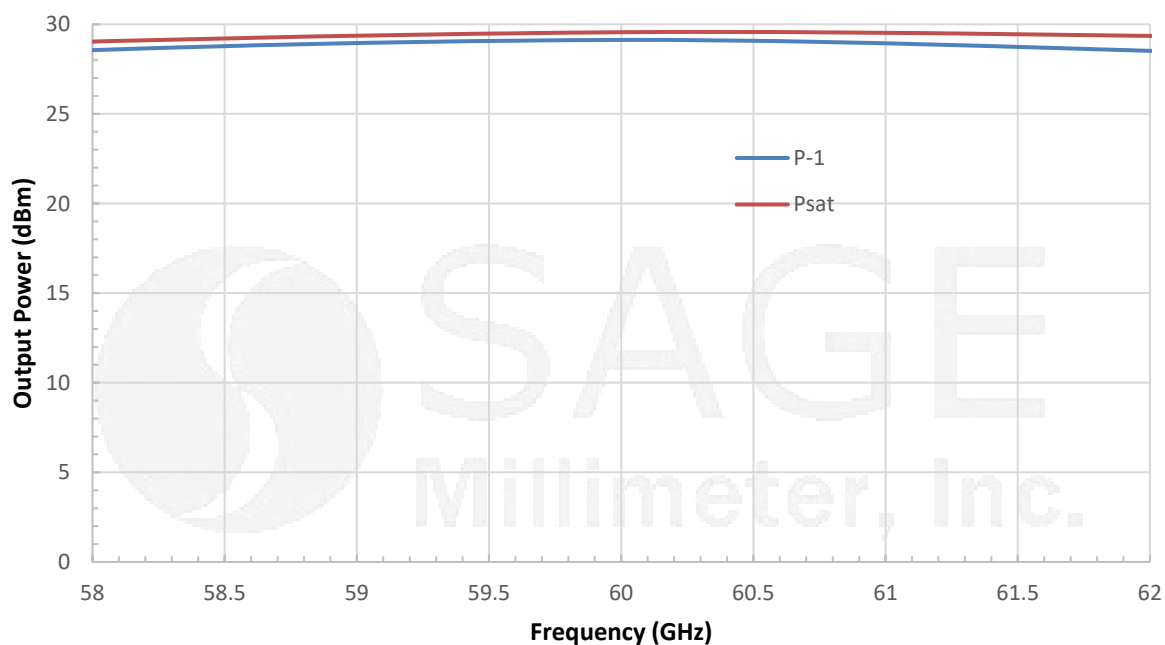
Gain and Return Loss vs. Frequency

Bias: +8 V_{DC}/2.9A



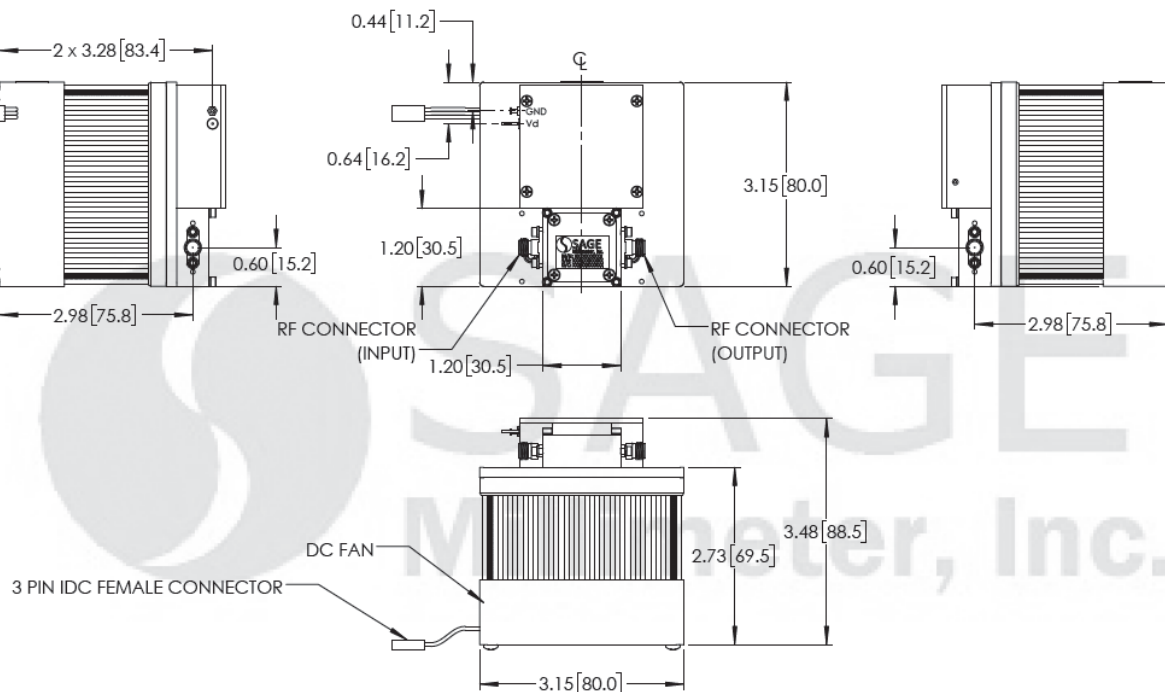
Output Power vs. Frequency

Bias: +8 V_{DC}/ 4.5 A



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Mechanical Outline: (Unless otherwise specified, all dimensions are in inches [millimeters])



Note:

- All data presented is collected from a sample lot. Actual data may vary unit to unit.
- All testing was performed under +25 °C case temperature.
- Eravant reserves the right to change the information presented without notice.
- Other mechanical configurations are available under different model numbers.

Caution:

- Exceeding absolute maximum ratings shown will damage the device.
- The device is static sensitive. Always follow ESD rules when working with the device.
- The case temperature of the device shall never exceed +50 °C. Use proper heatsink or fan if necessary.
- Any foreign objects in the waveguide will cause performance degradation and may damage the device.